

2021 Virtual School on Electron-Phonon Physics and the EPW code

June 14-18 2021



U.S. DEPARTMENT OF
ENERGY

TACC

Lecture Tue.1

Introduction to electron-phonon interactions

Feliciano Giustino

Oden Institute & Department of Physics

The University of Texas at Austin

- Heuristic approach to the electron-phonon interaction
- Examples of electron-phonon interactions
- Rayleigh-Schrödinger perturbation theory
- The electron-phonon matrix element
- Wannier interpolation

Where do electron-phonon interactions come from?

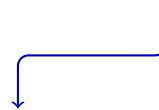
$$-\frac{\hbar^2}{2m_e} \nabla^2 \psi_n + V_{\text{SCF}} \psi_n = E_n \psi_n$$

Ionic degrees of freedom in the Kohn-Sham equations

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Atom κ at position τ_{κ}

Heuristic approach to electron-phonon interactions

The SCF potential depends **parametrically** on the atomic coordinates

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Perturbation Hamiltonian leading to EPIs

Manifestations of electron-phonon interactions

Electron mobility in monolayer MoS₂

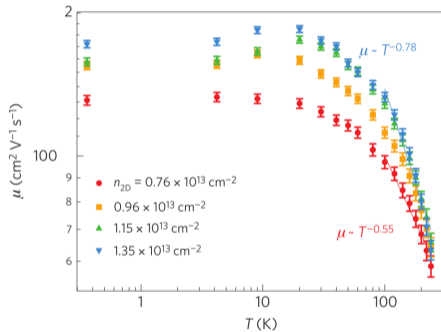
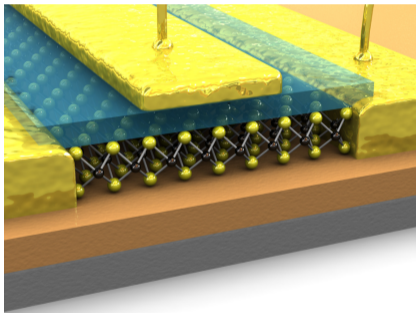
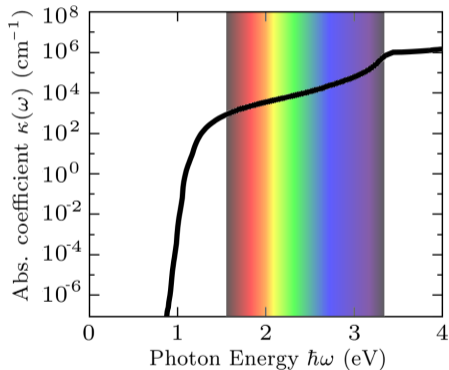


Figure from Radisavljevic and Kis, Nature Mater. 12, 815 (2013)

Manifestations of electron-phonon interactions

Phonon-assisted optical absorption in silicon



Data from Green et al, Prog. Photovolt. Res. Appl. 3, 189 (1995)

Manifestations of electron-phonon interactions

High-temperature superconductivity in compressed H_3S

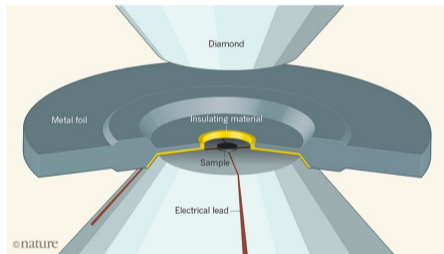
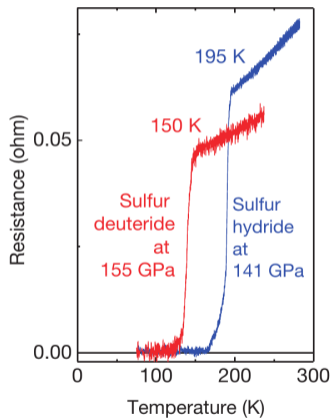


Figure from Drozdov et al, Nature 73, 525 (2015)

Manifestations of electron-phonon interactions

Temperature-dependent photoluminescence in hybrid perovskites

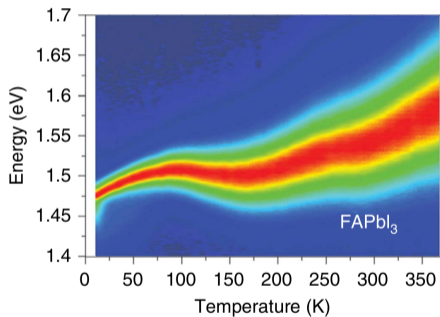
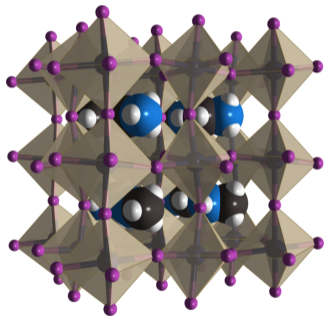
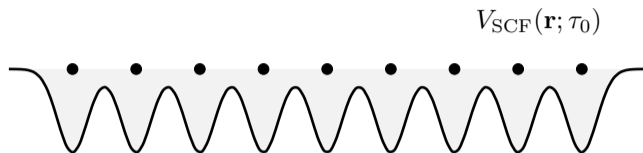
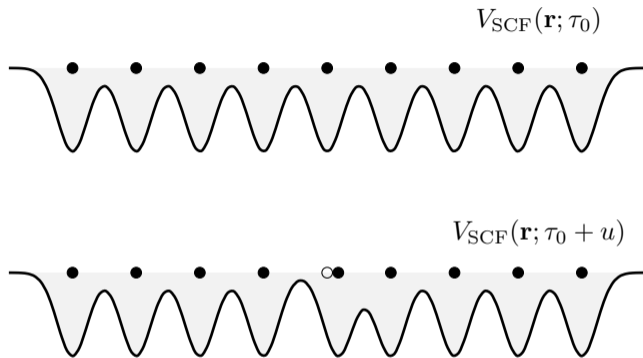


Figure from Wright et al, Nat. Commun. 7, 11755 (2016)

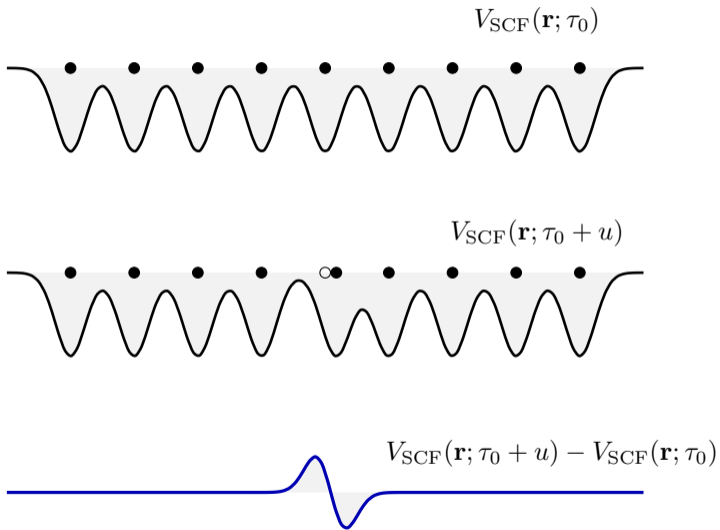
Perturbation Hamiltonian leading to EPIs



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Rayleigh-Schrödinger perturbation theory

Energy

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Transition rate $\Gamma_{n \rightarrow m} = \frac{2\pi}{\hbar} |\langle m | \frac{\partial V_{\text{SCF}}}{\partial \tau} u | n \rangle|^2 \delta(E_m - E_n - \hbar\omega)$

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Temperature-dependent band structure

Wavefunction $\Delta \psi_n(\mathbf{r}) = \sum_{m \neq n} \frac{\langle m | \frac{\partial V_{\text{SCF}}}{\partial \tau} u | n \rangle}{E_n - E_m} \psi_m(\mathbf{r})$

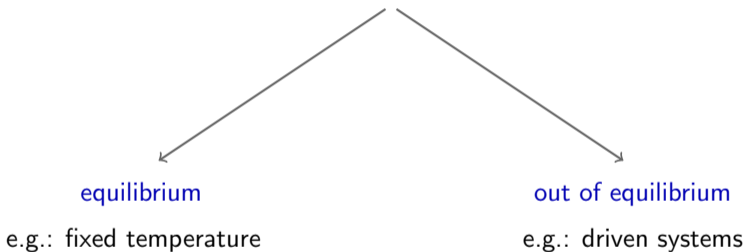
Phonon-assisted optical processes and polarons

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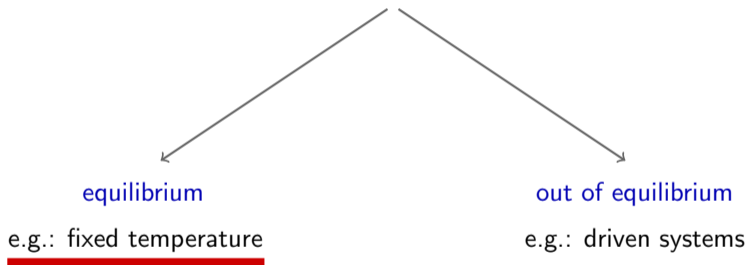
Phonon-limited transport phenomena

What is the atomic displacement u in the perturbation Hamiltonian?

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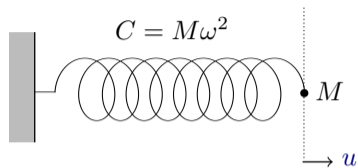


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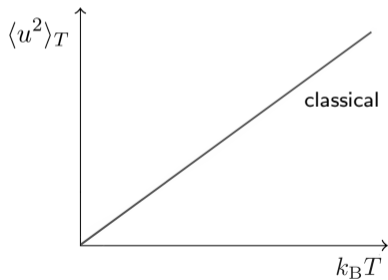
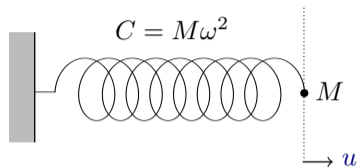


Mean square displacement amplitudes

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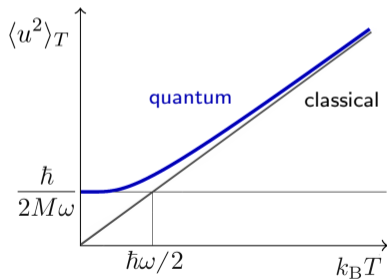
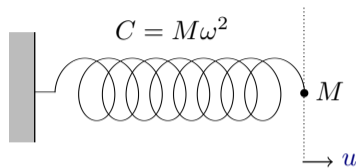


Mean square displacement amplitudes



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$$\langle u^2 \rangle_T = \frac{\hbar}{2M\omega} [2n(\hbar\omega/k_B T) + 1]$$

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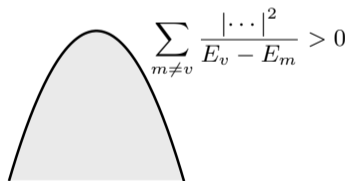
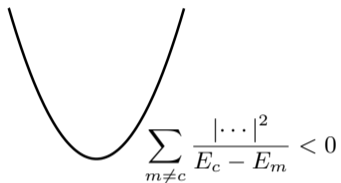
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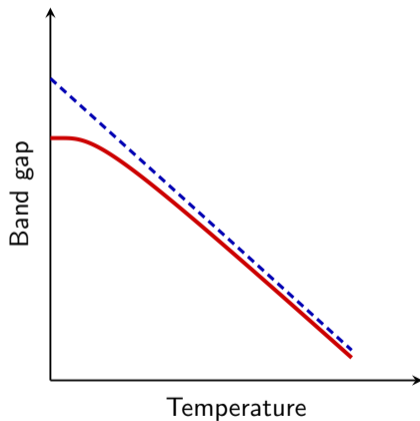
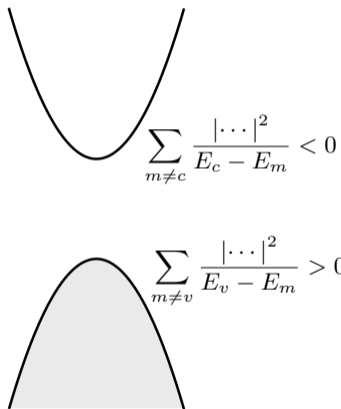
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Temperature-dependent band structures: Basic trends



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Example: Temperature-dependent bands of silicon

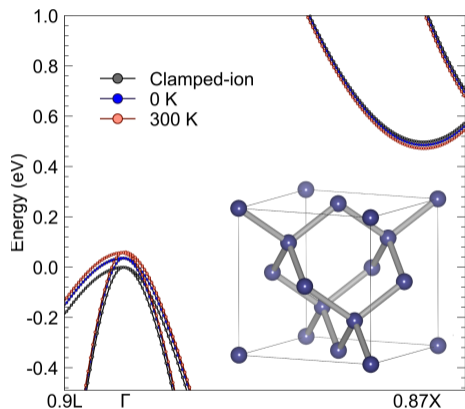


Figure from Zacharias et al, Phys. Rev. Research 2, 013357 (2020)

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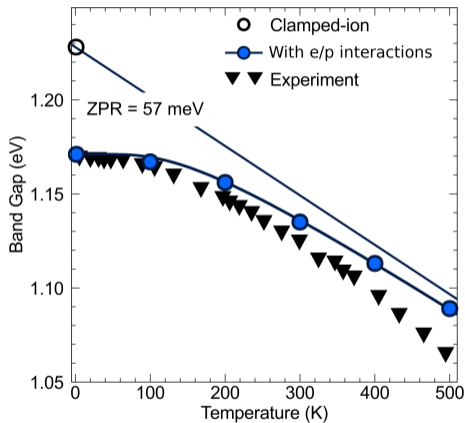
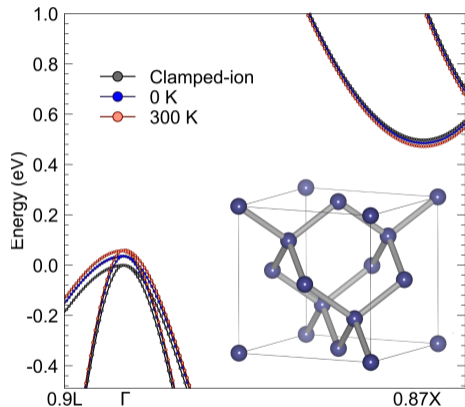


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Phonon-assisted optical absorption

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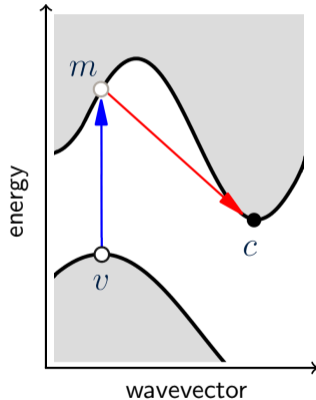
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Example: Absorption spectrum of silicon

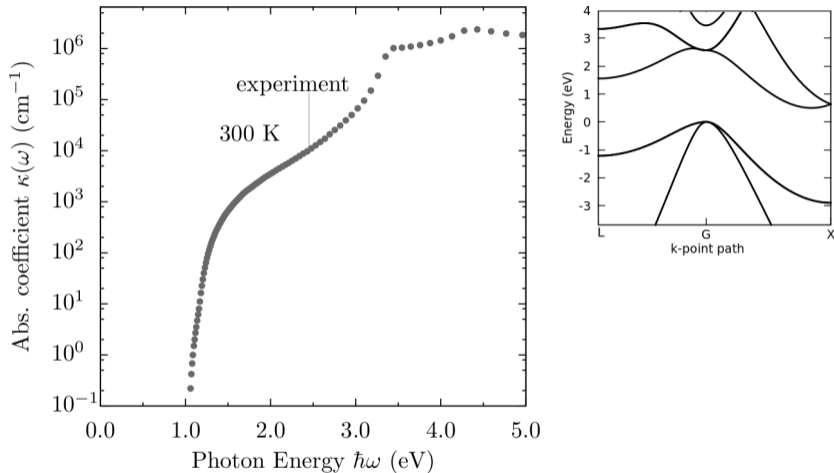


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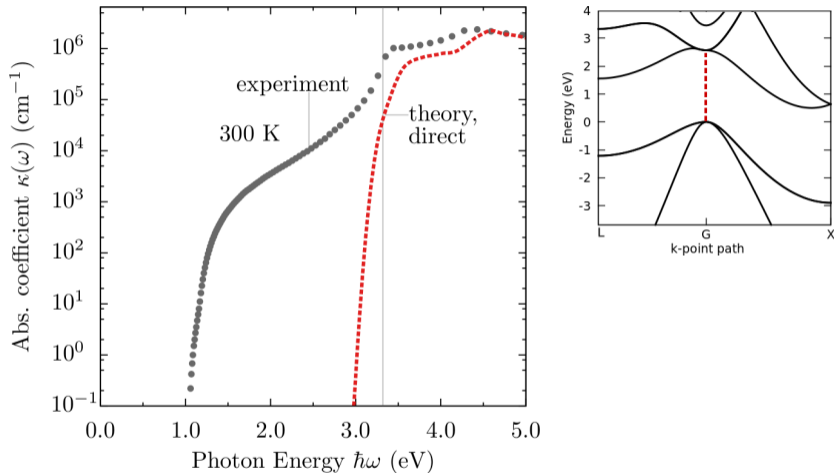


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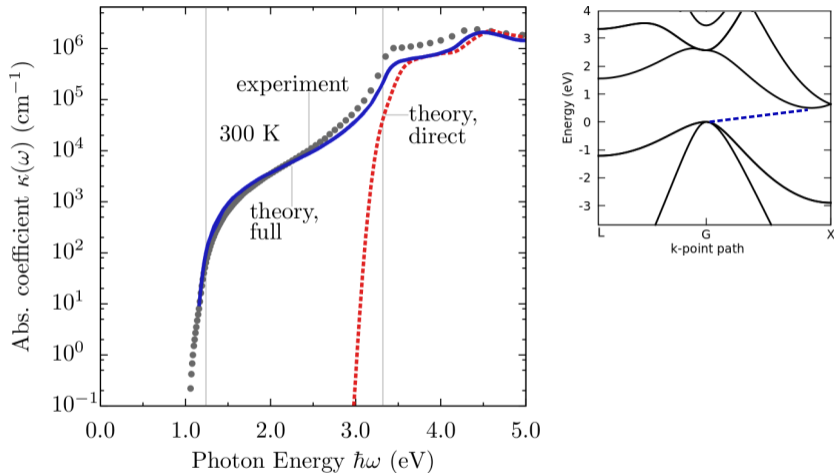


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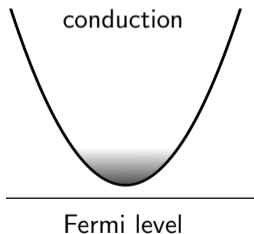
Carrier relaxation time

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Electron mobility from Boltzmann equation (simplified)



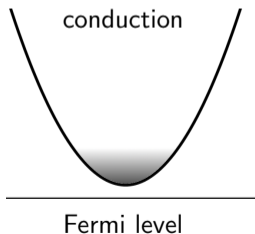
$$\mu_e = \frac{e}{m} \frac{1}{N_c} \sum_{n \in c} \frac{m |\mathbf{v}_n|^2}{3 k_B T} e^{-(E_n - E_F)/k_B T} \tau_n$$

Phonon-limited carrier mobilities

Carrier relaxation time

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Electron mobility from Boltzmann equation (simplified)



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↓

$$\mu = \frac{e \langle \tau \rangle}{m} \quad \text{Drude formula}$$

Example: Mobility of lead-halide perovskite MAPbI_3

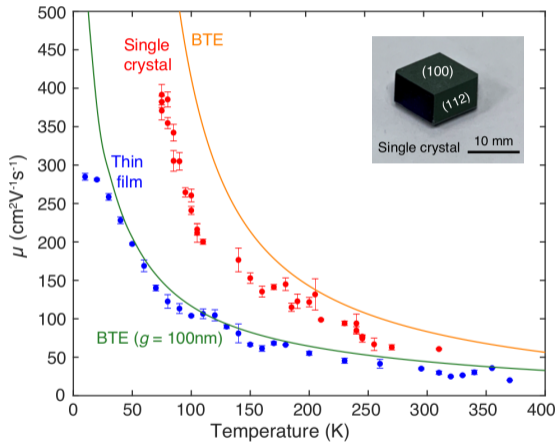


Figure from Xia et al, J. Phys. Chem. Lett. 12, 3607 (2021)

The electron-phonon matrix element

$$\langle \psi_m | \frac{\partial V_{\text{SCF}}}{\partial \tau} | \psi_n \rangle \longrightarrow g_{mn\nu}(\mathbf{k}, \mathbf{q}) = \langle u_{m\mathbf{k}+\mathbf{q}} | \Delta_{\mathbf{q}\nu} v_{\text{SCF}} | u_{n\mathbf{k}} \rangle_{\text{uc}}$$

Baroni et al, Rev. Mod. Phys. 73, 515 (2001); Giustino, Rev. Mod. Phys. 89, 015003 (2017)

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Lattice-periodic part of the wavefunction



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Lattice-periodic part of the wavefunction

Lattice-periodic variation
of the self-consistent potential

$$\Delta_{\mathbf{q}\nu} v_{\text{SCF}} = \sum_{\kappa\alpha p} e^{-i\mathbf{q}\cdot(\mathbf{r}-\mathbf{R}_p)} \sqrt{\frac{\hbar}{2M_\kappa\omega_{\mathbf{q}\nu}}} e_{\kappa\alpha,\nu}(\mathbf{q}) \frac{\partial V_{\text{SCF}}(\mathbf{r})}{\partial \tau_{\kappa\alpha p}}$$

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Lattice-periodic part of the wavefunction

Lattice-periodic variation
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Potential change
from ionic displacement

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The electron-phonon matrix element

$$\langle \psi_m | \frac{\partial V_{\text{SCF}}}{\partial \tau} | \psi_n \rangle \longrightarrow g_{mn\nu}(\mathbf{k}, \mathbf{q}) = \langle u_{m\mathbf{k}+\mathbf{q}} | \Delta_{\mathbf{q}\nu} v_{\text{SCF}} | u_{n\mathbf{k}} \rangle_{\text{uc}}$$

Lattice-periodic part of the wavefunction

Lattice-periodic variation
of the self-consistent potential

Potential change
from ionic displacement

$$\Delta_{\mathbf{q}\nu} v_{\text{SCF}} = \sum_{\kappa\alpha p} e^{-i\mathbf{q}\cdot(\mathbf{r}-\mathbf{R}_p)} \sqrt{\frac{\hbar}{2M_\kappa\omega_{\mathbf{q}\nu}}} e_{\kappa\alpha,\nu}(\mathbf{q}) \frac{\partial V_{\text{SCF}}(\mathbf{r})}{\partial \tau_{\kappa\alpha p}}$$

Phonon
polarization

Baroni et al, Rev. Mod. Phys. 73, 515 (2001); Giustino, Rev. Mod. Phys. 89, 015003 (2017)

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Incommensurate
modulation

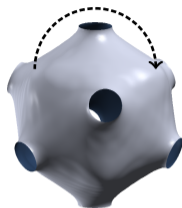
Phonon
polarization

Baroni et al, Rev. Mod. Phys. 73, 515 (2001); Giustino, Rev. Mod. Phys. 89, 015003 (2017)

Brillouin Zone integrals

Example: electron lifetimes in metals (adiabatic, high temperature)

$$\frac{1}{\tau_{n\mathbf{k}}} = 2k_{\text{B}}T \frac{2\pi}{\hbar} \sum_{m\nu} \int_{\text{BZ}} \frac{d\mathbf{q}}{\Omega_{\text{BZ}}} \frac{|g_{nm\nu}(\mathbf{k}, \mathbf{q})|^2}{\hbar\omega_{\mathbf{q}\nu}} \delta(\varepsilon_{n\mathbf{k}} - \varepsilon_{m\mathbf{k}+\mathbf{q}})$$

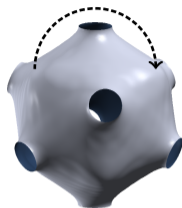


Fermi surface of copper

Brillouin Zone integrals

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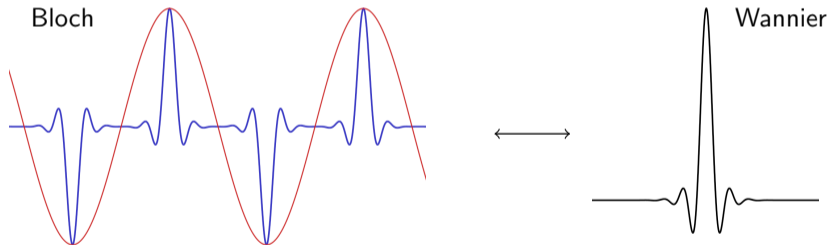
Fermi surface of copper

- The integral over the Brillouin zone can require grids with $100 \times 100 \times 100$ \mathbf{q} -points and more: **expensive**
- Each \mathbf{q} -vector requires a separate DFPT calculation: **expensive**

Wannier interpolation of electron-phonon matrix elements

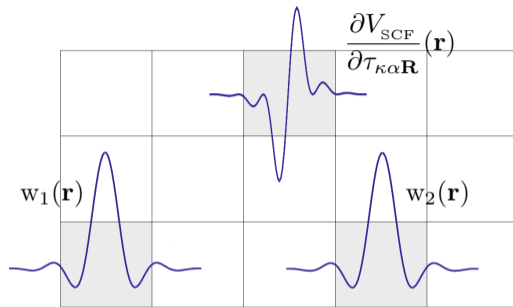
Wannier functions

$$w_{mp}(\mathbf{r}) = \frac{1}{N_p} \sum_{n\mathbf{k}} e^{-i\mathbf{k}\cdot\mathbf{R}_p} U_{nm\mathbf{k}} \psi_{n\mathbf{k}}(\mathbf{r})$$



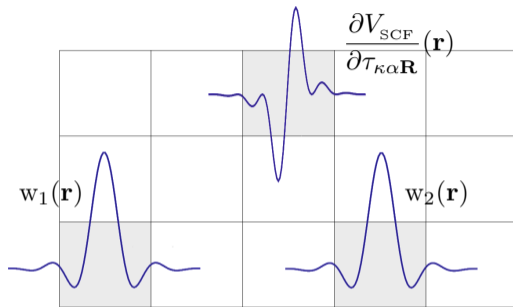
Marzari et al, Rev. Mod. Phys. 84, 1419 (2012)

Wannier interpolation of electron-phonon matrix elements



FG, Rev. Mod. Phys. 89, 015003 (2017)

Wannier interpolation of electron-phonon matrix elements



$$\mathbf{g}_\nu(\mathbf{k}, \mathbf{q}) = \sqrt{\frac{\hbar}{2M_\kappa\omega_{\mathbf{q}\nu}}} \sum_{\mathbf{R}\mathbf{R}'} e^{i(\mathbf{k}\cdot\mathbf{R}+\mathbf{q}\cdot\mathbf{R}')} U_{\mathbf{k}+\mathbf{q}} \mathbf{g}(\mathbf{R}, \mathbf{R}') \cdot \mathbf{e}_{\mathbf{q}\nu} U_{\mathbf{k}}^\dagger$$

FG, Rev. Mod. Phys. 89, 015003 (2017)

Example: Electron-phonon matrix elements of diamond

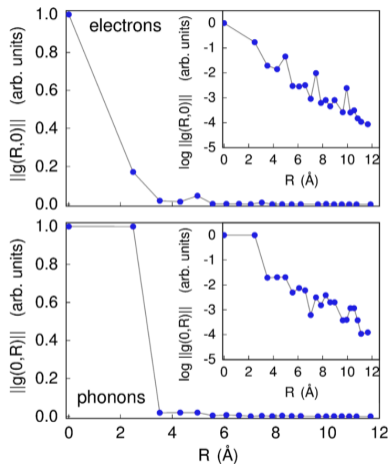


Figure from FG et al, Phys. Rev. B 76, 165108 (2007)

Example: Electron-phonon matrix elements of diamond

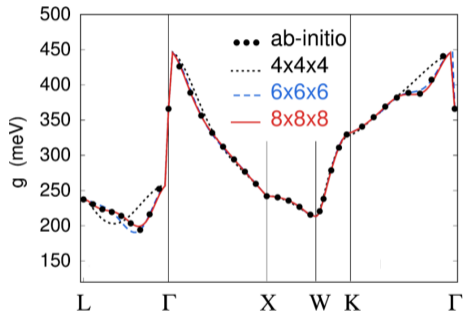
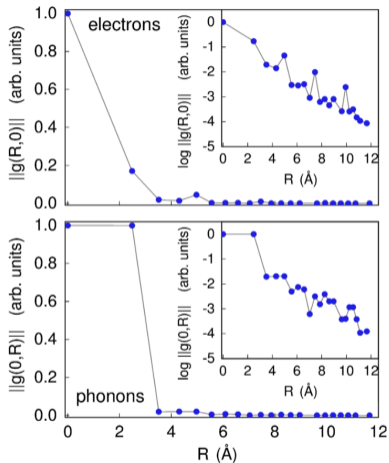
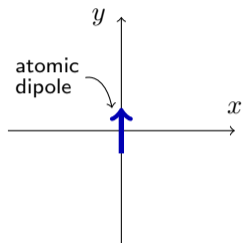
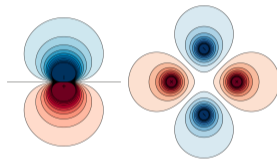


Figure from FG et al, Phys. Rev. B 76, 165108 (2007)

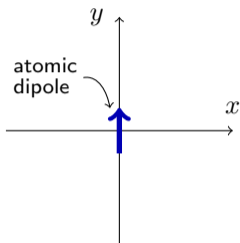
Spatial decay of induced potential



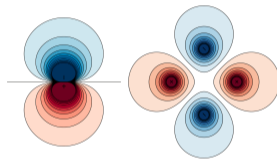
$$\frac{\partial V_{\text{SCF}}}{\partial \tau}(\mathbf{r}) \sim \epsilon^{-1} \left[\begin{array}{ccc} \text{dipole} & \text{quadrupole} & \text{octupole} \\ D_{\alpha} \frac{\hat{r}_{\alpha}}{r^2} & + Q_{\alpha\beta} \frac{\hat{r}_{\alpha} \hat{r}_{\beta}}{r^3} & + O_{\alpha\beta\gamma} \frac{\hat{r}_{\alpha} \hat{r}_{\beta} \hat{r}_{\gamma}}{r^4} + \dots \end{array} \right]$$



Spatial decay of induced potential

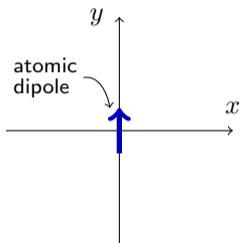


$$\frac{\partial V_{\text{SCF}}}{\partial \tau}(\mathbf{r}) \sim \epsilon^{-1} \left[\overset{\text{dipole}}{D_{\alpha}} \frac{\hat{r}_{\alpha}}{r^2} + \overset{\text{quadrupole}}{Q_{\alpha\beta}} \frac{\hat{r}_{\alpha}\hat{r}_{\beta}}{r^3} + \overset{\text{octupole}}{O_{\alpha\beta\gamma}} \frac{\hat{r}_{\alpha}\hat{r}_{\beta}\hat{r}_{\gamma}}{r^4} + \dots \right]$$

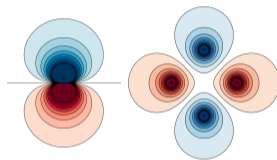


Fourier: $\frac{1}{q}$ 1 q

Spatial decay of induced potential



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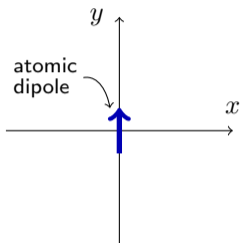


Fourier: $\frac{1}{q}$ 1 q

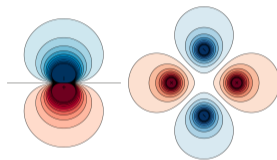
Metals: $\epsilon(q) = 1 + \frac{q_{\text{TF}}^2}{q^2}$

Insulator: $\epsilon(q) = 1 + \frac{\epsilon_0 - 1}{1 + q^2/q_0^2}$

Spatial decay of induced potential



$$\frac{\partial V_{\text{SCF}}}{\partial \tau}(\mathbf{r}) \sim \epsilon^{-1} \left[D_{\alpha} \frac{\hat{r}_{\alpha}}{r^2} + Q_{\alpha\beta} \frac{\hat{r}_{\alpha} \hat{r}_{\beta}}{r^3} + O_{\alpha\beta\gamma} \frac{\hat{r}_{\alpha} \hat{r}_{\beta} \hat{r}_{\gamma}}{r^4} + \dots \right]$$



Fourier: $\frac{1}{q}$ 1 q

Metals:	$\epsilon(q) = 1 + \frac{q_{\text{TF}}^2}{q^2}$	smooth	smooth	smooth
Insulator:	$\epsilon(q) = 1 + \frac{\epsilon_0 - 1}{1 + q^2/q_0^2}$	singular	discontinuous	smooth

Example: Fröhlich interaction matrix element in TiO_2

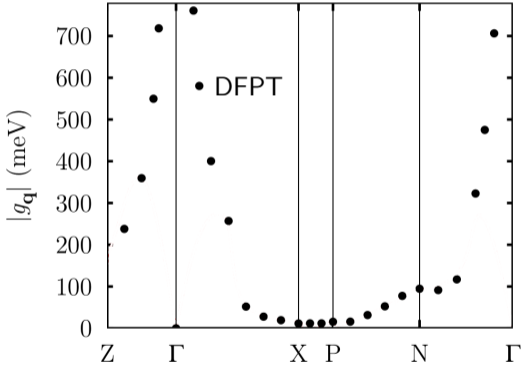
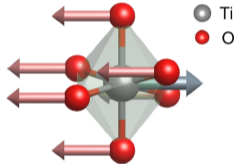


Figure from Verdi et al, Phys. Rev. Lett. 115, 176401 (2015)

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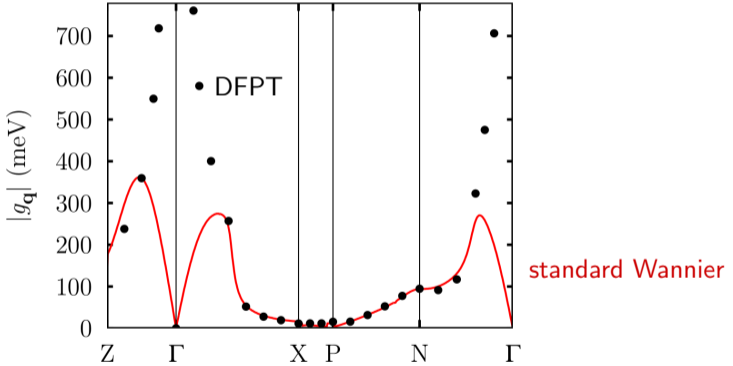
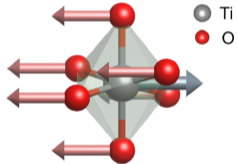


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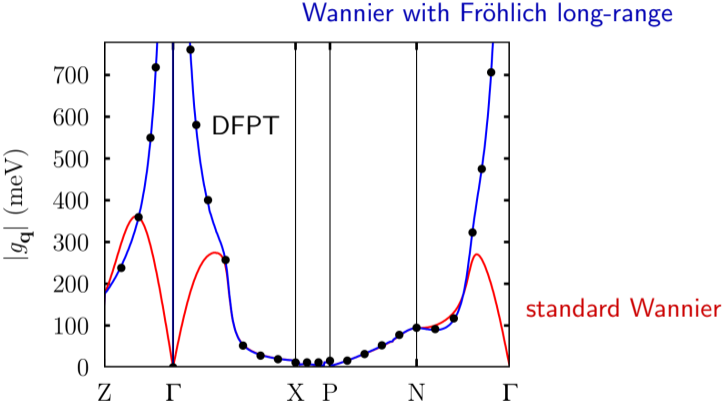
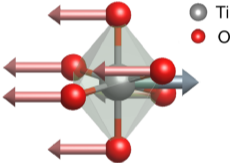


Figure from Verdi et al, Phys. Rev. Lett. 115, 176401 (2015)

Take-home messages

- We can understand the basics of electron-phonon physics using elementary perturbation theory
- Calculations of EPIs require a fine sampling of the electron-phonon matrix elements across the Brillouin zone
- The EPI matrix elements of metals and insulators behave very differently for long-wavelength phonons

- Grimvall, *The electron-phonon interaction in metals*, 1981 (North-Holland)
- Giustino, Rev. Mod. Phys. 89, 015003 (2017) [\[link\]](#)
- Baroni et al, Rev. Mod. Phys. 73, 515 (2001) [\[link\]](#)
- Marzari et al, Rev. Mod. Phys. 84, 1419 (2012) [\[link\]](#)
- Verdi et al, Phys. Rev. Lett. 115, 176401 (2015) [\[link\]](#)
- Sjakste et al, Phys. Rev. B 92, 054307 (2015) [\[link\]](#)
- Brunin et al, Phys. Rev. Lett. 125, 136601 (2020) [\[link\]](#)
- Jhalani et al, Phys. Rev. Lett. 125, 136602 (2020) [\[link\]](#)